



13003DH

Preliminary

NPN SILICON TRANSISTOR

NPN SILICON BIPOLAR TRANSISTORS FOR LOW FREQUENCY AMPLIFICATION

DESCRIPTION

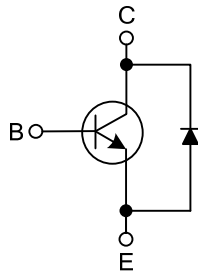
The UTC **13003DH** is a silicon NPN power switching transistor; it uses UTC's advanced technology to provide customers high collector-base breakdown voltage, low reverse leakage current and high reliability, etc.

The UTC **13003DH** is suitable for electronic ballast power switch circuit and the compact electronic energy-saving light.

FEATURES

- * High collector-base breakdown voltage
- * Low reverse leakage current
- * High reliability

EQUIVALENT CIRCUIT

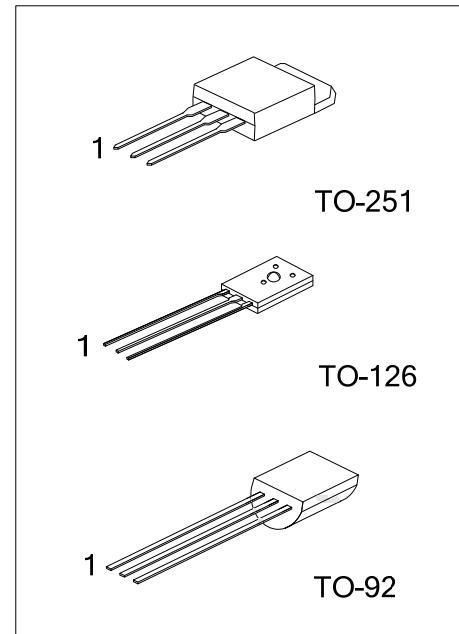


ORDERING INFORMATION

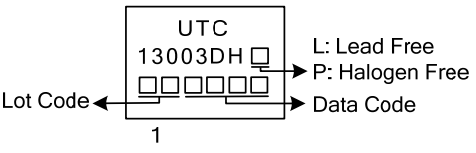
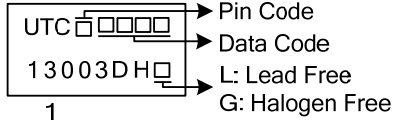
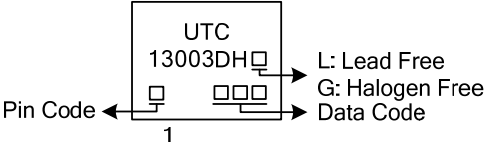
Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
13003DHL-x-TM3-T	13003DHG-x-TM3-T	TO-251	B	C	E	Tube
13003DHL-x-T60-F-K	13003DHG-x-T60-F-K	TO-126	B	C	E	Bulk
13003DHL-x-T92-A-B	13003DHG-x-T92-A-B	TO-92	E	C	B	Tape Box
13003DHL-x-T92-A-K	13003DHG-x-T92-A-K	TO-92	E	C	B	Bulk

Note: Pin Assignment: B: Base C: Collector E: Emitter

13003DHL-T60-F-B	(1)Packing Type (2)Pin Assignment (3)Package Type (4)Lead Free	(1) T: Tube, B: Bulk, K: Bulk (2) refer to Pin Assignment (3) TM3: TO-251, T60: TO-126, T92: TO-92 (4) L: Lead Free, G: Halogen Free
------------------	---	---



■ MARKING INFORMATION

PACKAGE	MARKING
TO-251	 Diagram showing marking on a TO-251 package. The marking includes 'UTC', '13003DH', and a lot code '1' followed by four squares. Arrows indicate: Lot Code points to the '1'; L: Lead Free points to the 'H'; P: Halogen Free points to the 'D'; Data Code points to the last square of the lot code.
TO-126	 Diagram showing marking on a TO-126 package. The marking includes 'UTC', a pin code '1' followed by three squares, '13003DH', and a data code '1' followed by two squares. Arrows indicate: Pin Code points to the '1'; Data Code points to the last square of the pin code; L: Lead Free points to the 'H'; G: Halogen Free points to the 'D'.
TO-92	 Diagram showing marking on a TO-92 package. The marking includes 'UTC', '13003DH', a pin code '1' followed by two squares, and a data code '1' followed by two squares. Arrows indicate: Pin Code points to the '1'; L: Lead Free points to the 'H'; G: Halogen Free points to the 'D'; Data Code points to the last square of the pin code.

■ **ABSOLUTE MAXIMUM RATINGS** ($T_A=25^{\circ}\text{C}$, unless otherwise noted)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V _{CBO}	600	V
Collector-Emitter Voltage		V _{CEO}	400	V
Emitter-Base Voltage		V _{EBO}	9	V
Continuous Collector Current		I _C	1.8	A
Power Dissipation	T _A =25°C	P _D	1.25	W
	T _C =25°C		50	W
Junction Temperature		T _J	150	°C
Storage Temperature Range		T _{STG}	-55~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **ELECTRICAL CHARACTERISTICS** ($T_A=25^{\circ}\text{C}$, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV_{CBO}	$I_C=0.1\text{mA}$	600			V
Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C=1\text{mA}$	400			V
Emitter-Base Breakdown Voltage	BV_{EBO}	$I_E=0.1\text{mA}$	9			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=600\text{V}$, $I_E=0$			0.1	mA
Collector-Emitter Cut-Off Current	I_{CEO}	$V_{CE}=400\text{V}$, $I_B=0$			0.1	mA
Emitter-Base Cut-Off Current	I_{EBO}	$V_{EB}=9\text{V}$, $I_C=0$			0.1	mA
DC Current Gain (Note 1)	h_{FE}	$I_C=0.2\text{A}$, $V_{CE}=5.0\text{V}$	15		30	
Low current and high current h_{FE2} h_{FE1} ratio	h_{FE1}/h_{FE2}	h_{FE1} : $V_{CE}=5\text{V}$, $I_C=5\text{mA}$	0.75	0.9		
		h_{FE2} : $V_{CE}=5\text{V}$, $I_C=0.2\text{A}$				
Collector-Emitter Saturation Voltage (Note)	$V_{CE(SAT)}$	$I_C=1\text{A}$, $I_B=0.25\text{A}$		0.30	0.8	V
Base-Emitter Saturation Voltage (Note)	$V_{BE(SAT)}$	$I_C=1\text{A}$, $I_B=0.25\text{A}$		0.9	1.2	V
Storage Time	t_s	UI9600, $I_C=0.1\text{A}$	3		5	μs
Rise Time	t_R				1	μs
Fall Time	t_F				1	μs
Transition Frequency	f_T	$I_C=0.1\text{A}$, $V_{CE}=10\text{V}$, $f=1\text{MHz}$	5			MHz
Diode Forward Voltage	V_F	$I_F=1.5\text{A}$			2.5	V

Note: Pulse test, pulse width $t_p \leq 300\mu\text{s}$, Duty cycles $\leq 2\%$

■ **CLASSIFICATION OF h_{FE}**

RANK	A	B	C
RANGE	15 ~ 20	20 ~ 25	25 ~ 30

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.